## Tracker simulation

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Components	Radius(mm)	Half Z (mm)	σ <sub>Rφ</sub> (μm)	σ <sub>Z</sub> (μ <b>m)</b>	Thickness(X <sub>0</sub> %)
Beam Pipe	10.35	-	-	-	0.172
VTX (3 double layers)	12.3/14.4/35.5/37.5/58.3/60.3		2.8/6/4/4/4/4	2.8/6/4/4/4/4	0.155
VTX-shell	65		-	-	0.139
SITs (3 layers)	150/250/500	740/1340/1890	7.2	86.6	0.650
DC inner wall	610	2980	-	-	0.110
DC cell (66 x18x18)	612-1800	-	100	2828	0.00127×66
DC outer wall	1802	-	-	-	1.349
SET	1811	2980	7.2	86.6	0.182

pt resolution of ITK

固定z向pitch 为200um, Rphi向pitch分别 取15、25、50um

### 固定Rphi向pitch 为25um,z向pitch分别取 100、200、300um



theta resolution of ITK

固定z向pitch 为200um, Rphi向pitch分别 取15、25、50um

#### 固定Rphi向pitch 为25um, z向pitch分别取 100、200、300um



pt resolution of OTK

固定z向pitch 为200um, Rphi向pitch分别 取15、25、50um

### 固定Rphi向pitch 为25um,z向pitch分别取 200um、20mm、20cm



theta resolution of OTK

固定z向pitch 为200um, Rphi向pitch分别 取15、25、50um

### 固定Rphi向pitch 为25um, z向pitch分别取 200um、20mm、20cm



Components	Z (mm)	Rin(mm)	Rout(mm)	σ <sub>Rφ</sub> (mm)	σ <sub>R</sub> (mm)	Thickness(X <sub>0</sub> %)
VXD	200					0.65
SIT1	740	105	150	7.2	86.6	0.65
SIT2	1340	191	250	7.2	86.6	0.65
SIT3	1890	269	500	7.2	86.6	0.65
SET	2915	424	1811	7.2	86.6	0.65

pt resolution of endcap

固定R向pitch 为300um, phi向pitch分别取 25、50、100um

### 固定phi向pitch 为25um, R向pitch分别取 100um、300um、1000um



固定R向pitch 为300um, phi向pitch分别取 25、50、100um

#### 固定phi向pitch 为25um, z向pitch分别取 100um、300um、1000um



### Pt spectrum



### Low momentum tracks

- Fractions of low pt tracks (pt<1GeV && pt> 0.1 GeV)
  - $e+e- \rightarrow \mu\mu H$ : 42%
  - $e+e- \rightarrow qqH$ : 46%
  - $e+e- \rightarrow Z \rightarrow bb: 51\%$
- Lots of tracks of p < 1 GeV hardly reaches ToF due to material and decay effect</li>
  Based on CDR detector



Curling when pt < 0.8 GeV (even larger due to materials)

## pt distribution of tracks with p < 1 GeV



## PID performance with only ToF



### Tracks can reach ToF

Barrel or End cap	qqH(%) (3T)	mmH(%)(3T)	Z <b>→qq (2T)(%)</b>
Barrel	34.5	32.3	48.9
End cap	46.4	42.1	49.7

Barrel :  $|\cos theta| < 0.85$ 

Barrel (3T): pt > 0.81 GeV & p < 3. GeV Endcap (3T): pt > 0.20 GeV & p < 3. GeV Barrel (2T): pt > 0.54 GeV & p < 3. GeV Endcap (2T): pt > 0.20 GeV & p < 3. GeV

### contribution of d0&dpt for dp



 $(dp/p)^2 = (dpt/pt)^2 + (d\theta/tan\theta)^2$ 

θ:32°~86°, 31.8°是OTK边缘的角度

pt=2GeV时, dθ/tanθ 的值约为 dpt/pt 的1/3; pt=10、100GeV时, 两者差别在一个数量级以 上

# d0 in different z pitch of ITK&OTK





改变ITK 和OTK的z向分辨对 θ的分辨 影响都较小